
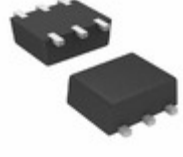
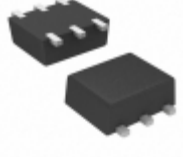
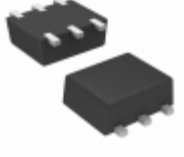
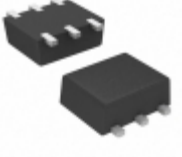
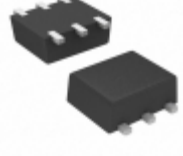
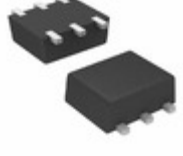

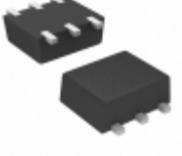
	<h2>SI1070X-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1070X-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Electro-Films (EFI) / Vishay</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 1.2A SOT563F</p> <p><b>Datenblätter:</b>  <a href="#">SI1070X-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 183870 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1070X-T1-GE3</a>
Hersteller	<a href="#">Electro-Films (EFI) / Vishay</a>
Beschreibung	MOSFET N-CH 30V 1.2A SOT563F
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	183870 pcs Stock
Hersteller Standard Vorlaufzeit	33 Weeks
detaillierte Beschreibung	N-Channel 30V 236mW (Ta) Surface Mount SC-89-6
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SC-89-6
Verlustleistung (max)	236mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	99 mOhm @ 1.2A, 4.5V
VGS (th) (Max) @ Id	1.55V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	8.3nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	385pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1070X-T1-GE3CT




SI1070X-T1-GE3 ist neu im Original, Suche SI1070X-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1070X-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1070X-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1071X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 0.96A SOT563F</p>	 <p><b>SI1069X-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 0.94A SC89-6</p>	 <p><b>SI1070X-T1-E3</b> Vishay / Siliconix MOSFET N-CH 30V 1.2A SOT563F</p>	 <p><b>SI1070X-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 30V 1.2A SOT563F</p>
 <p><b>SI1071X-T1-E3</b> Vishay / Siliconix MOSFET P-CH 30V 0.96A SOT563F</p>	 <p><b>SI1070X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 1.2A SOT563F</p>	 <p><b>SI1069X-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 0.94A SC89-6</p>	 <p><b>SI1071X-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 0.96A SC89-6</p>

### heiße Teile

Mehr

 SI1050X-T1-E3	 SI1050X-T1-GE3	 SI1050X-T1-GE3	 SI1051X-T1-GE3	 SI1051X-T1-GE3
 SI1056X-T1-E3	 SI1056X-T1-E3	 SI1056X-T1-GE3	 SI1056X-T1-GE3	 SI1058X-T1-GE3
 SI1058X-T1-GE3	 SI1065X-T1-E3	 SI1065X-T1-E3	 SI1065X-T1-GE3	 SI1065X-T1-GE3
 SI1067X-T1-E3	 SI1067X-T1-E3	 SI1067X-T1-GE3	 SI1067X-T1-GE3	 SI1069X-T1-E3
 SI1069X-T1-E3	 SI1069X-T1-GE3	 SI1069X-T1-GE3	 SI1070X-T1-E3	 SI1070X-T1-E3
 SI1070X-T1-GE3	 SI1071X-T1-GE3	 SI1071X-T1-GE3	 SI1072X-T1-E3	 SI1072X-T1-E3
 SI1072X-T1-GE3	 SI1072X-T1-GE3	 SI1073X-T1-GE3	 SI1073X-T1-GE3	 SI1120-A-GMR
 SI1132-A10-GMR	 SI1133-AA00-GMR	 SI1133DP-T1-GE3	 SI1141-A10-GMR	 SI1142-A11-GMR
 SI1143-A11-GMR	 SI1143-M01-GMR	 SI1144-AAGX-GMR	 SI1300BDL-T1-E3	 SI1300BDL-T1-E3
 SI1300BDL-T1-GE3	 SI1300BDL-T1-GE3	 SI1300DL	 SI1300DL-T1	 SI1300DL-T1-GE3

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited

